µPG2411T7C

GaAs Integrated Circuit
SPDT Switch for 2 GHz to 6 GHz

DESCRIPTION

The µPG2411T7C is a GaAs MMIC SPDT (Single Pole Double Throw) switch which was designed for 2 GHz to 6 GHz applications, including dual-band wireless LAN.

This device can operate at frequencies from 2 GHz to 6 GHz, having the low insertion loss and high isolation.

This device is housed in a 6-pin plastic RTSON (Rectangle Thin Small Out-line Non-leaded) package. And this package is suitable for high-density surface mounting.

FEATURES

- Switch control voltage : $V_{cont (H)}$ = 3.0 V TYP.
  : $V_{cont (L)}$ = 0 V TYP.
- Low insertion loss : L_{ins} = 0.50 dB TYP. @ f = 2.5 GHz
  : L_{ins} = 0.70 dB TYP. @ f = 6.0 GHz
- High isolation : ISL = 25 dB TYP. @ f = 2.5 GHz
  : ISL = 25 dB TYP. @ f = 6.0 GHz
- Handling power : $P_{in (1 dB)}$ = +30.5 dBm TYP. @ f = 2.5 GHz
  : $P_{in (1 dB)}$ = +30.5 dBm TYP. @ f = 6.0 GHz
- High-density surface mounting : 6-pin plastic RTSON package ($2.0 \times 1.3 \times 0.37$ mm)

APPLICATIONS

- Wireless LAN (IEEE802.11a/b/g/n)

ORDERING INFORMATION

| Part Number	Order Number	Package	Marking	Supplying Form
µPG2411T7C-E3	µPG2411T7C-E3-A	6-pin plastic RTSON (Pb-Free)	G6G	• Embossed tape 8 mm wide • Pin 1, 2, 3 face the perforation side of the tape • Qty 3 kpcs/reel

Remark To order evaluation samples, please contact your nearby sales office.

Part number for sample order: µPG2411T7C-A

PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM

Pin No.	Pin Name
1	RF1
2	GND
3	RF2
4	$V_{cont}2$
5	RFC
6	$V_{cont}1$

Remark Exposed pad : GND
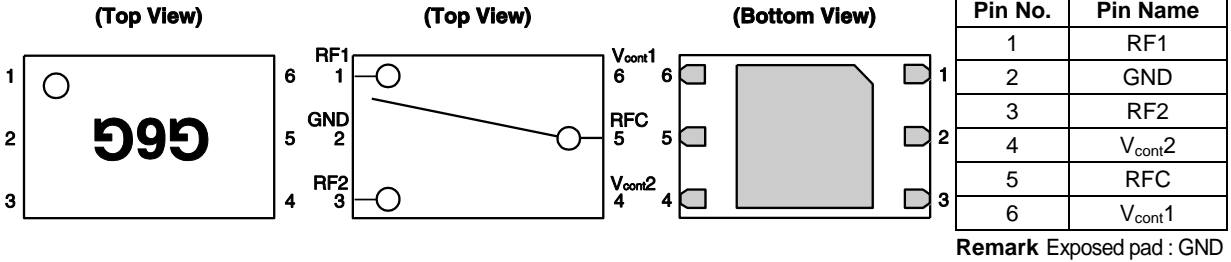
SW TRUTH TABLE

ON Path	$V_{cont}1$	$V_{cont}2$
RFC-RF1	High	Low
RFC-RF2	Low	High

ABSOLUTE MAXIMUM RATINGS (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Switch Control Voltage	V_{cont}	+6.0 **Note**	V
Input Power	P_{in}	+31.0	dBm
Power Dissipation	P_D	150	mW
Operating Ambient Temperature	T_A	−40 to +90	°C
Storage Temperature	T_{stg}	−55 to +150	°C

Note: $|V_{cont}1 - V_{cont}2| \leq 6.0$ V

RECOMMENDED OPERATING RANGE (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Operating Frequency	f	2.0	–	6.0	GHz
Switch Control Voltage (H)	$V_{cont\,(H)}$	2.8	3.0	3.3	V
Switch Control Voltage (L)	$V_{cont\,(L)}$	−0.2	0	0.2	V
Control Voltage Difference	$\Delta V_{cont\,(H)}$, $\Delta V_{cont\,(L)}$ **Note**	−0.1	0	0.1	V

Note: $\Delta V_{cont\,(H)} = V_{cont}1_{\,(H)} - V_{cont}2_{\,(H)}$
       $\Delta V_{cont\,(L)} = V_{cont}1_{\,(L)} - V_{cont}2_{\,(L)}$

ELECTRICAL CHARACTERISTICS
(T_A = +25°C, $V_{cont (H)}$ = 3.0 V, $V_{cont (L)}$ = 0 V, Z_O = 50 Ω, DC blocking capacitors = 8 pF, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Insertion Loss	L_{ins}	f = 2.4 to 2.5 GHz	–	0.50	0.8	dB
		f = 4.9 to 6.0 GHz	–	0.70	1.0	dB
Isolation	ISL	f = 2.4 to 2.5 GHz	20	25	–	dB
		f = 4.9 to 6.0 GHz	20	25	–	dB
Return Loss	RL	f = 2.4 to 2.5 GHz	11	17	–	dB
		f = 4.9 to 6.0 GHz	11	17	–	dB
1 dB Loss Compression Input Power [Note]	$P_{in (1 dB)}$	f = 2.5 GHz	–	+30.5	–	dBm
		f = 6.0 GHz	–	+30.5	–	dBm
2nd Harmonics	2f0	f = 2.5 GHz, P_{in} = +20 dBm	–	80	–	dBc
		f = 6.0 GHz, P_{in} = +20 dBm	–	70	–	dBc
3rd Harmonics	3f0	f = 2.5 GHz, P_{in} = +20 dBm	–	80	–	dBc
		f = 6.0 GHz, P_{in} = +20 dBm	–	70	–	dBc
Switch Control Current	I_{cont}	No RF input	–	0.1	1.0	μA
Switch Control Speed	t_{SW}	50% CTL to 90/10% RF	–	20	100	ns

Note: $P_{in (1 dB)}$ is the measured input power level when the insertion loss increases 1 dB more than that of the linear range.

CAUTION

It is necessary to use DC blocking capacitors with this device.

The value of DC blocking capacitors should be chosen to accommodate the frequency of operation, bandwidth, switching speed and the condition with actual board of your system.
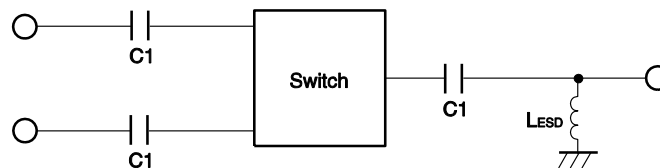

RENESAS

EVALUATION CIRCUIT
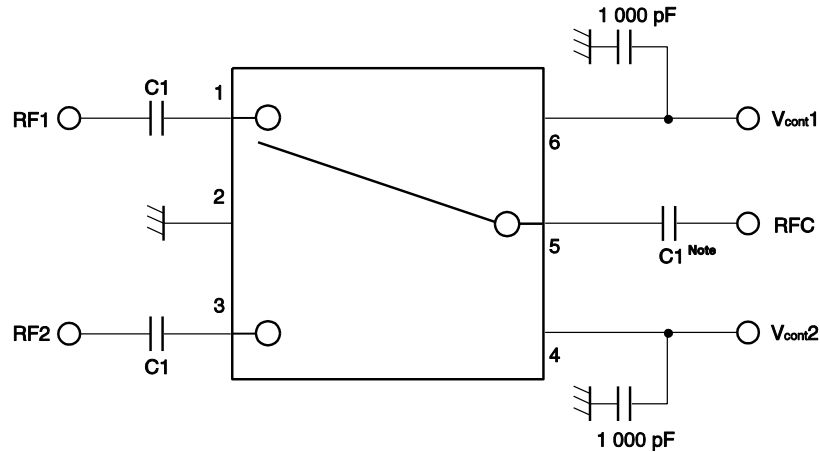
Note: C1: 8 pF

The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.
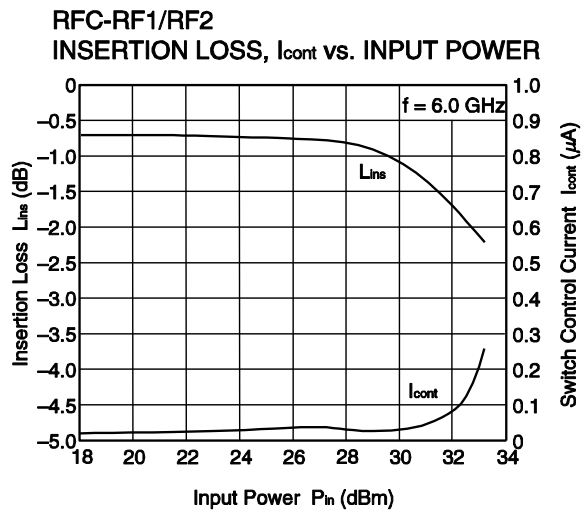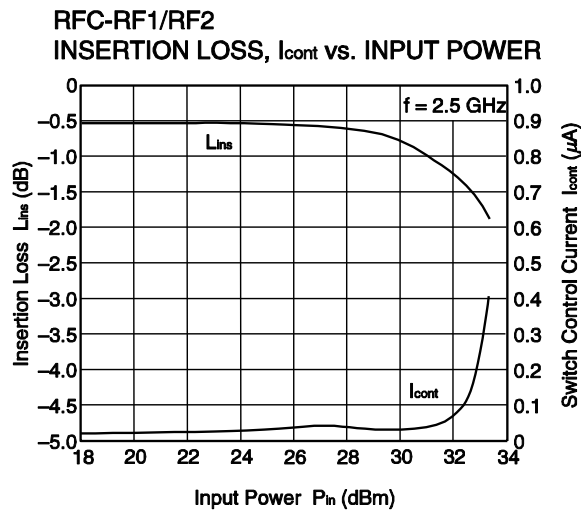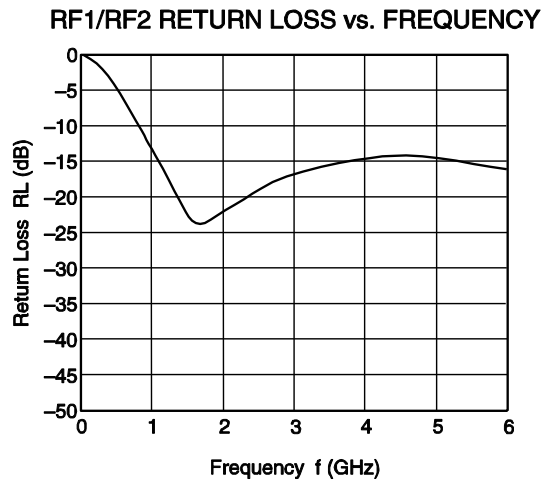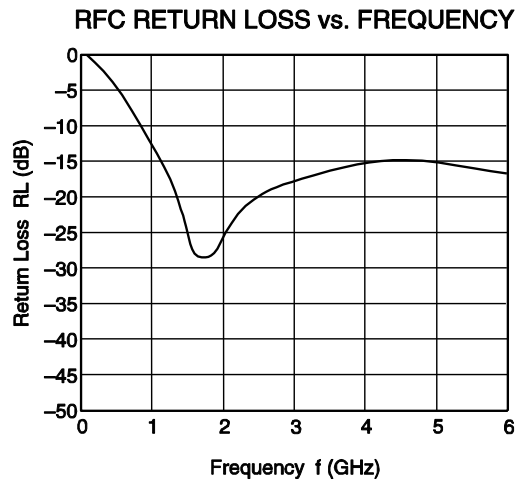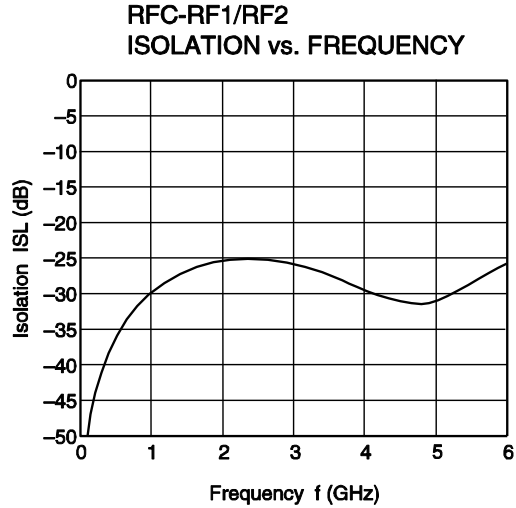
APPLICATION INFORMATION
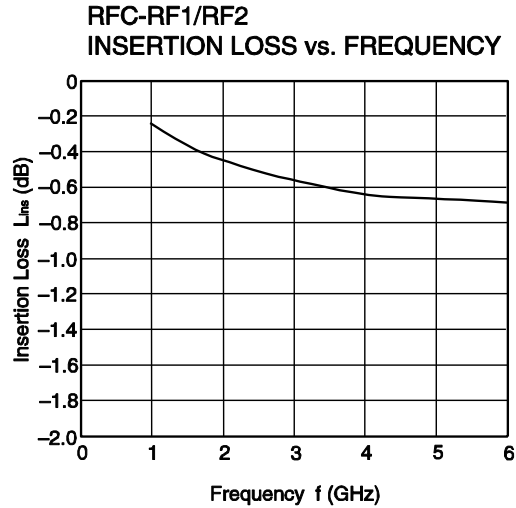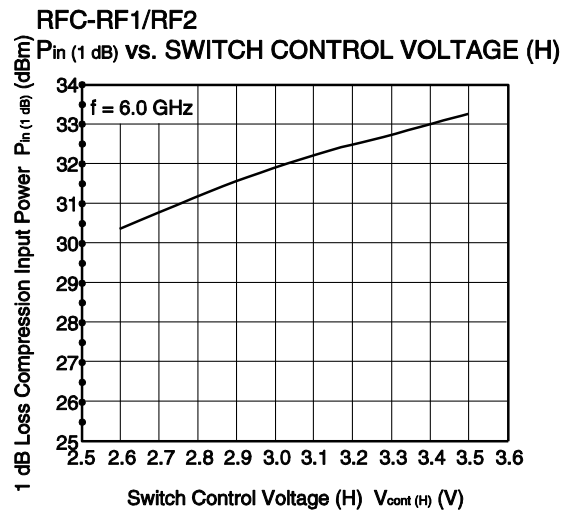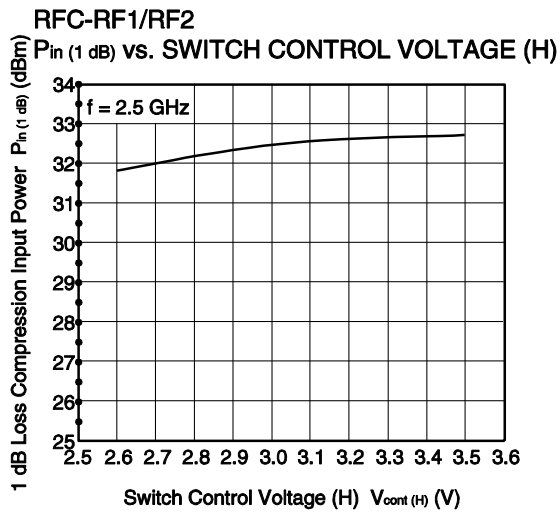

- C1 are DC blocking capacitors external to the device.
  The value may be tailored to provide specific electrical responses.
- The RF ground connections should be kept as short as possible and connected to directly to a good RF ground for best performance.
- L_{ESD} provides a means to increase the ESD protection on a specific RF port, typically the port attached to the antenna.

TYPICAL CHARACTERISTICS
(T_A = +25°C, $V_{cont (H)}$ = 3.0 V, $V_{cont (L)}$ = 0 V, Z_O = 50 Ω, DC blocking capacitors = 8 pF, unless otherwise specified)

RFC-RF1/RF2
INSERTION LOSS vs. FREQUENCY

RFC-RF1/RF2
ISOLATION vs. FREQUENCY

RFC RETURN LOSS vs. FREQUENCY

RF1/RF2 RETURN LOSS vs. FREQUENCY

RFC-RF1/RF2
INSERTION LOSS, I_{cont} vs. INPUT POWER

RFC-RF1/RF2
INSERTION LOSS, I_{cont} vs. INPUT POWER

Remark The graphs indicate nominal characteristics.

RENESAS

RFC-RF1/RF2
$P_{in\ (1\ dB)}$ vs. SWITCH CONTROL VOLTAGE (H)

RFC-RF1/RF2
$P_{in\ (1\ dB)}$ vs. SWITCH CONTROL VOLTAGE (H)

Remark The graphs indicate nominal characteristics.

PACKAGE DIMENSIONS

6-PIN PLASTIC RTSON (UNIT: mm)

(Top View)

2.0±0.1

1.3±0.1

(Side View)

$0.37^{+0.03}_{-0.05}$

(Bottom View)

1.1±0.1

(C0.15)

$0.15^{+0.07}_{-0.05}$

0.08 MIN.

0.5±0.06

A

A

1.14±0.1

0.2±0.1

Remark A>0

( ): Reference value

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions		Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature)	: 260°C or below	IR260
	Time at peak temperature	: 10 seconds or less	
	Time at temperature of 220°C or higher	: 60 seconds or less	
	Preheating time at 120 to 180°C	: 120±30 seconds	
	Maximum number of reflow processes	: 3 times	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	
Partial Heating	Peak temperature (terminal temperature)	: 350°C or below	HS350
	Soldering time (per side of device)	: 3 seconds or less	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	

CAUTION

Do not use different soldering methods together (except for partial heating).

Caution GaAs Products	This product uses gallium arsenide (GaAs).
	GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
	
	• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
	
	  1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
	
	  2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
	
	• Do not burn, destroy, cut, crush, or chemically dissolve the product.
	
	• Do not lick the product or in any way allow it to enter the mouth.

			Description
Revision History			**µPG2411T7C Data Sheet**

Rev.	**Date**	**Page**	**Summary**
1.00	Jun 17, 2010	–	First edition issued